

MSM80C31F/MSM80C51F

CMOS 8-Bit Microcontroller

GENERAL DESCRIPTION

The OKI MSM80C31F/MSM80C51F microcontroller is a low-power, 8-bit device implemented in OKI's silicon-gate complementary metal-oxide semiconductor process technology. The device includes 4K bytes of mask programmable ROM (MSM80C51F only), 128 bytes of data RAM, 32 I/O lines, two 16-bit timer/counters, a five-source two-level interrupt structure, a full duplex serial port, and an oscillator and clock circuitry. In addition, the device has two software selectable modes for further power reduction — Idle and Power Down. Idle mode freezes the CPU's in-instruction execution while maintaining RAM and allowing the timers, serial port and interrupt system to continue functions. Power Down mode saves the RAM contents but freezes the oscillator causing all other device functions to be inoperative.

FEATURES

- Low power consumption by 2 μ m silicon gate CMOS process technology
- Fully static circuit
- Internal program memory : 4K bytes (MSM80C51F)
- External program memory space : 64K bytes
- Internal data memory (RAM) : 128 bytes
- External data memory (RAM) space : 64K bytes
- I/O ports : 8-bit $\times$ 4 ports
- Two 16-bit timer/counters
- Multifunctional serial port (UART)
- Five interrupt sources (Priority can be set)
- Four sets of working registers (R0-7 $\times$ 4)
- Stack : Internal data memory (RAM)
128-byte area can be used arbitrarily (by SP specified)
- Two CPU power-down modes
 - (1) Idle mode : CPU stopped while oscillation continued.
(Software setting)
 - (2) PD mode : CPU and oscillation all stopped.
(Software setting)
(Setting I/O ports to floating status possible)
- Operating temperature : -40 to +85°C (@ 12 MHz, $V_{CC} = 5\text{ V} \pm 20\%$)
-20 to +70°C (@ 16 MHz, $V_{CC} = 5\text{ V} \pm 5\%$)
- 2-byte 1-machine cycle instructions : 1 μ sec. @ 12 MHz
0.75 μ sec. @ 16 MHz
- Multiplication/division instructions : 4 μ sec. @ 12 MHz
3 μ sec. @ 16 MHz
- Instruction code addressing method
 - Byte specification : Data addressing (direct)
 - Bit specification : Bit addressing

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- Package options

40-pin plastic DIP (DIP40-P-600-2.54)	:	(MSM80C31F-xxxRS) (MSM80C51F-xxxRS)
44-pin plastic QFP (QFP44-P-910-0.80-2K)	:	(MSM80C31F-xxxGS) (MSM80C51F-xxxGS)
44-pin plastic QFJ (PLCC) (QFJ44-P-S650-1.27)	:	(MSM80C31F-xxxJS) (MSM80C51F-xxxJS)

xxx indicates the code number.

DIFFERENCES BETWEEN MSM80C31F/MSM80C51F AND MSM80C31/MSM80C51

- Operating frequency

0.5 to 16 MHz	MSM80C31F-1/MSM80C51F-1
0.5 to 12 MHz	MSM80C31/MSM80C51/MSM80C31F/MSM80C51F
- External clock input terminal

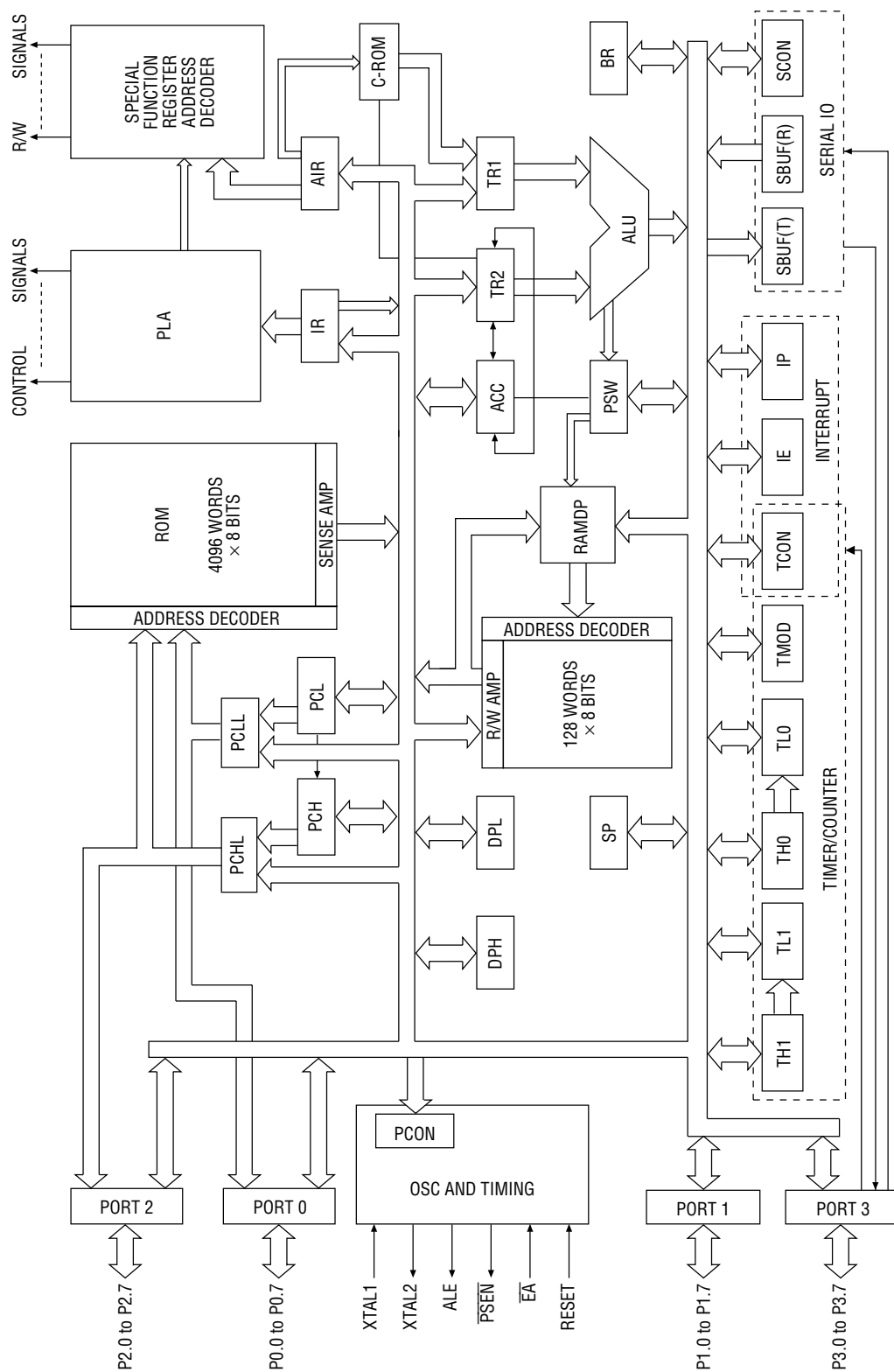
XTAL1	MSM80C31F(-1)/MSM80C51F(-1)
XTAL2	MSM80C31/MSM80C51
- Emulation mode

Output impedance of ALE and $\overline{\text{PSEN}}$ pins becomes about 20 k Ω while CPU is being reset in MSM80C31F/MSM80C51F.

Any other functions and electrical characteristics of MSM80C31F/MSM80C51F except for above three differences are the same as those of MSM80C31/MSM80C51.

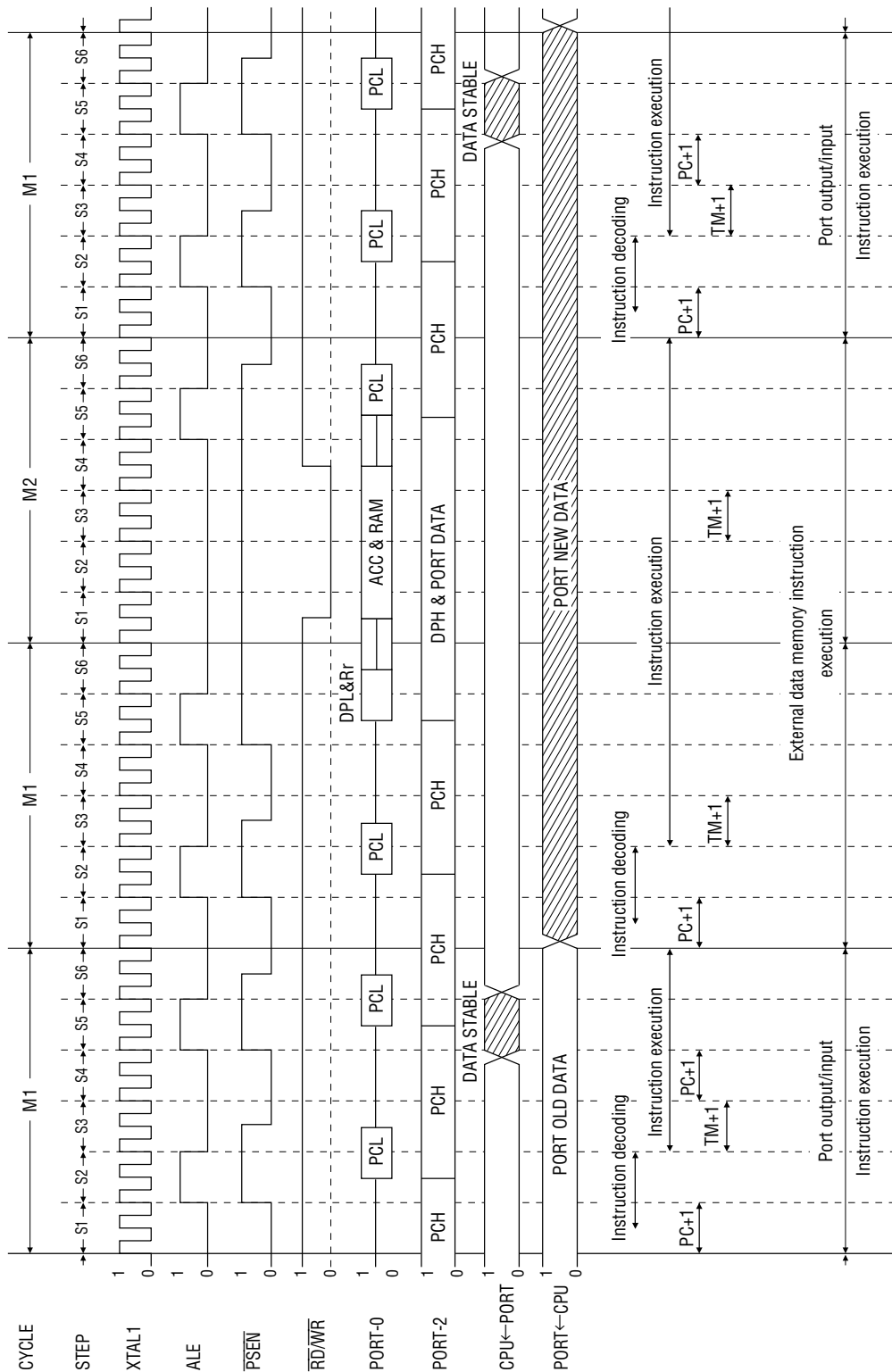
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BLOCK DIAGRAM



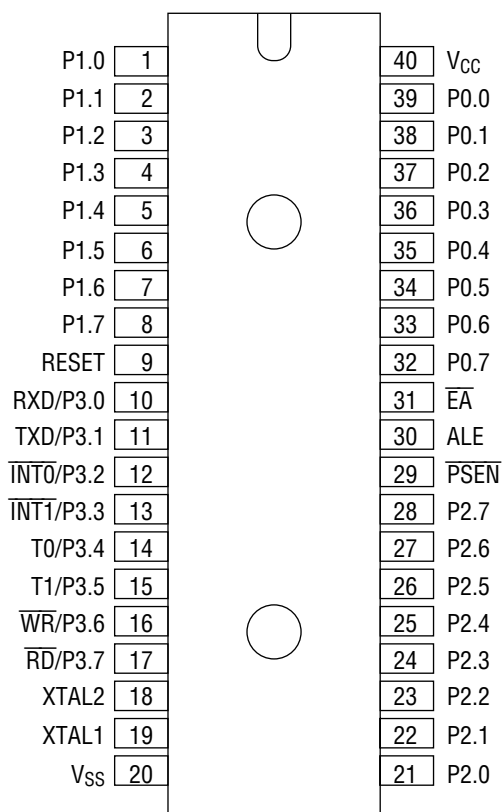
CLOCK WAVEFORMS

Basic Timing Chart



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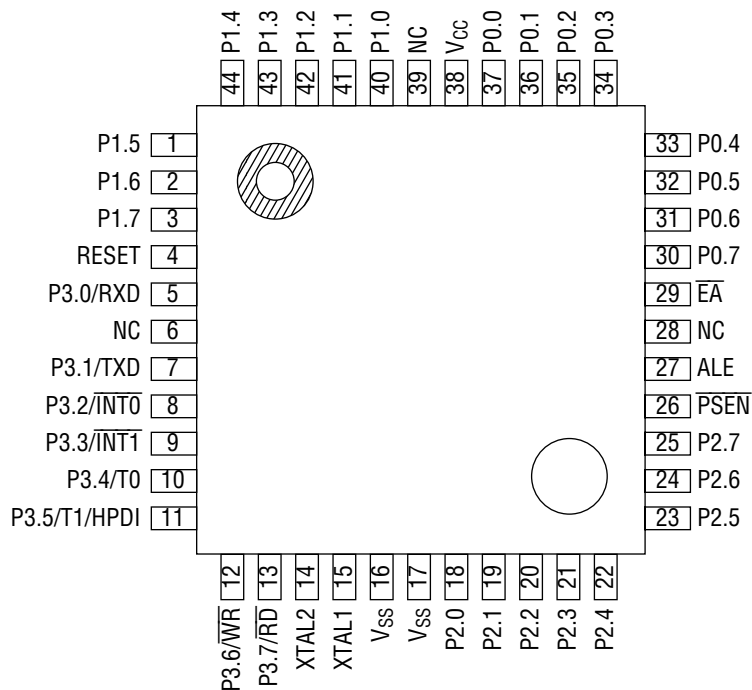
PIN CONFIGURATION (TOP VIEW)



40-Pin Plastic DIP

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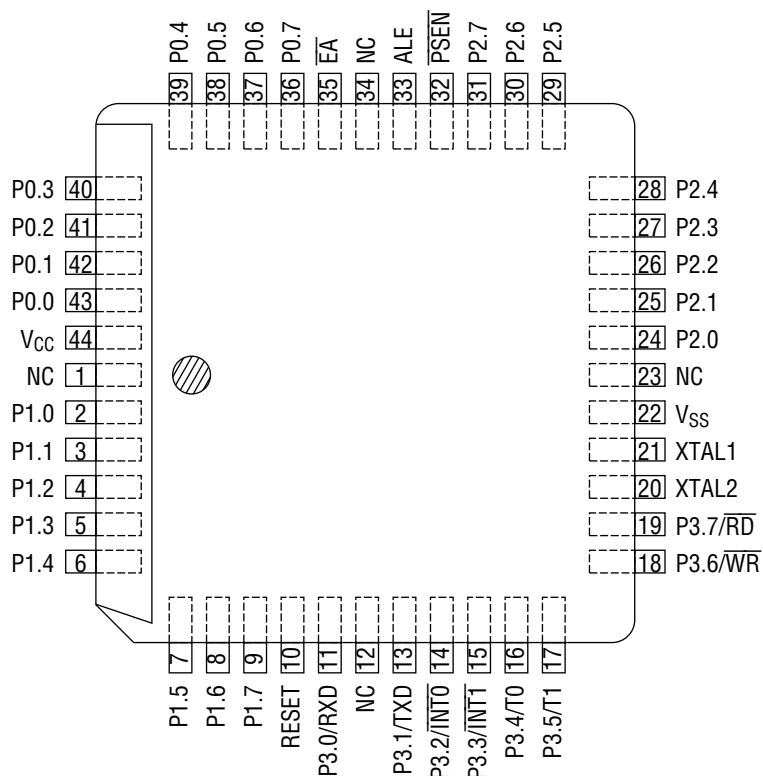
PIN CONFIGURATION (TOP VIEW) (continued)



44-Pin Plastic QFP

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PIN CONFIGURATION (TOP VIEW) (continued)



44-Pin Plastic QFJ (PLCC)

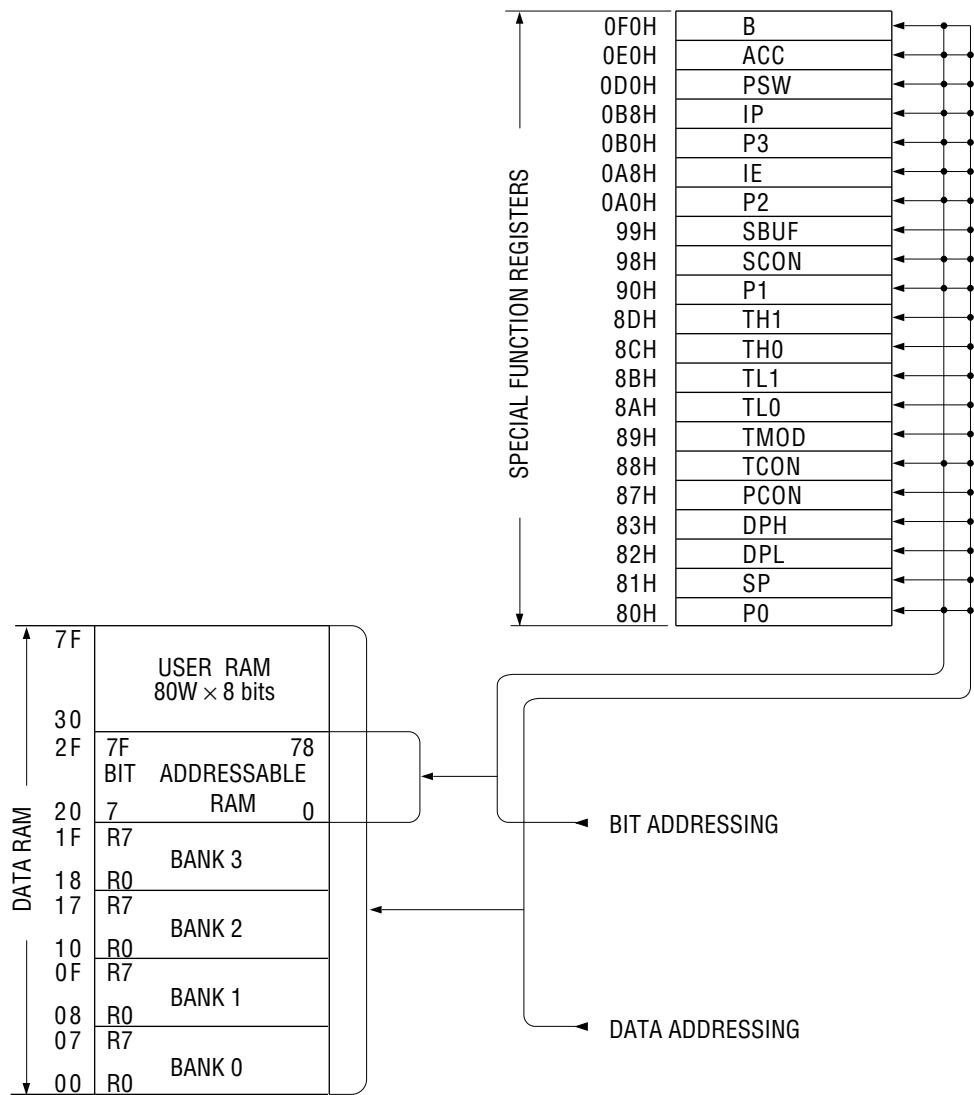
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PIN DESCRIPTION

Symbol	Description																		
V _{SS}	Ground potential																		
V _{CC}	Supply voltage during Normal, Idle and Power Down operation																		
Port 0.0 - 0.7	Port 0 is an 8-bit open-drain bidirectional I/O port. It is also the multiplexed low-order address and data bus during accesses to external memory.																		
Port 1.0 - 1.7	Port 1 is an 8-bit bidirectional I/O port with internal pull-ups. It can drive CMOS inputs without external pull-ups.																		
Port 2.0 - 2.7	Port 2 is an 8-bit bidirectional I/O port with internal pull-ups. It outputs the high-order address byte during accesses to external memory. It can drive CMOS inputs without external pull-ups.																		
Port 3.0 - 3.7	Port 3 is an 8-bit bidirectional I/O port with internal pull-ups. It also provides various special features, as shown below: <table> <tr> <th>Port Pin</th><th>Alternate Function</th></tr> <tr> <td>P3.0</td><td>RXD (serial input port)</td></tr> <tr> <td>P3.1</td><td>TXD (serial output port)</td></tr> <tr> <td>P3.2</td><td>INT0 (external interrupt)</td></tr> <tr> <td>P3.3</td><td>INT1 (external interrupt)</td></tr> <tr> <td>P3.4</td><td>T0 (Timer 0 external input)</td></tr> <tr> <td>P3.5</td><td>T1 (Timer 1 external input)</td></tr> <tr> <td>P3.6</td><td>WR (external data memory write strobe)</td></tr> <tr> <td>P3.7</td><td>RD (external data memory read strobe)</td></tr> </table> Port 3 can drive CMOS inputs without external pull-ups.	Port Pin	Alternate Function	P3.0	RXD (serial input port)	P3.1	TXD (serial output port)	P3.2	INT0 (external interrupt)	P3.3	INT1 (external interrupt)	P3.4	T0 (Timer 0 external input)	P3.5	T1 (Timer 1 external input)	P3.6	WR (external data memory write strobe)	P3.7	RD (external data memory read strobe)
Port Pin	Alternate Function																		
P3.0	RXD (serial input port)																		
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P3.2	INT0 (external interrupt)																		
P3.3	INT1 (external interrupt)																		
P3.4	T0 (Timer 0 external input)																		
P3.5	T1 (Timer 1 external input)																		
P3.6	WR (external data memory write strobe)																		
P3.7	RD (external data memory read strobe)																		
RESET	Reset input pin. A reset is accomplished by holding the RESET pin high for at least 1μs, even if the oscillator has been stopped. The CPU responds by executing an internal reset. An internal pull-down resistor permits Power-On reset using only a capacitor connected to V _{CC} . This pin does not receive the power down voltage since the function has been transferred to the V _{CC} pin.																		
ALE	Address Latch Enable. This output latches for latching the low byte of the address during accesses to external memory. For this purpose, ALE is activated twice every machine cycle or at a constant rate of 1/6th the oscillator frequency, except during an external memory access at which time one ALE pulse is skipped. ALE can drive CMOS inputs without an external pull-up.																		
$\overline{\text{PSEN}}$	Program Store Enable output. This output is the read strobe to external program memory. For this purpose, $\overline{\text{PSEN}}$ is activated twice every machine cycle. (However, when executing out of external program memory, two activations of $\overline{\text{PSEN}}$ are skipped during each access to external data memory.) $\overline{\text{PSEN}}$ is not activated during fetches from internal program memory. It can drive CMOS inputs without an external pull-up.																		
$\overline{\text{EA}}$	External Access input pin. When $\overline{\text{EA}}$ is held high, the CPU executes out of internal program memory (unless the program counter exceeds 0FFFH). When $\overline{\text{EA}}$ is held low, the CPU executes only out of external program memory. $\overline{\text{EA}}$ must not be floated.																		
XTAL1	Crystal 1 pin. It is an input to the inverting amplifier which forms the internal oscillator.																		
XTAL2	Crystal 2 pin. It is an output of the inverting amplifier that forms the internal oscillator.																		

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DATA MEMORY AND SPECIAL FUNCTION REGISTER LAYOUT DIAGRAM



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DETAILED DIAGRAM OF DATA MEMORY (RAM)

7FH	USER DATA RAM								127	BIT ADDRESSING	DATA ADDRESSING	INDIRECT ADDRESSING
30H									48			
2FH	7F	7E	7D	7C	7B	7A	79	78	47			
2EH	77	76	75	74	73	72	71	70	46			
2DH	6F	6E	6D	6C	6B	6A	69	68	45			
2CH	67	66	65	64	63	62	61	60	44			
2BH	5F	5E	5D	5C	5B	5A	59	58	43			
2AH	57	56	55	54	53	52	51	50	42			
29H	4F	4E	4D	4C	4B	4A	49	48	41			
28H	47	46	45	44	43	42	41	40	40			
27H	3F	3E	3D	3C	3B	3A	39	38	39			
26H	37	36	35	34	33	32	31	30	38			
25H	2F	2E	2D	2C	2B	2A	29	28	37			
24H	27	26	25	24	23	22	21	20	36			
23H	1F	1E	1D	1C	1B	1A	19	18	35			
22H	17	16	15	14	13	12	11	10	34			
21H	0F	0E	0D	0C	0B	0A	09	08	33			
20H	07	06	05	04	03	02	01	00	32			
1FH	Bank 3								31	REGISTER ADDRESSING		
18H												
17H	Bank 2								23			
10H												
0FH	Bank 1								15			
08H												
07H	Bank 0								7			
00H												

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DETAILED DIAGRAM OF SPECIAL FUNCITON REGISTERS

Data Address	Bit Address								Special Function Register Symbol
	(MSB)							(LSB)	
0F0H	F7	F6	F5	F4	F3	F2	F1	F0	B
0E0H	E7	E6	E5	E4	E3	E2	E1	E0	ACC
	CY	AC	F0	RS1	RS0	OV	F1	P	
0D0H	D7	D6	D5	D4	D3	D2	D1	D0	PSW
				PS	PT1	PX1	PT0	PX0	
0B8H	—	—	—	BC	BB	BA	B9	B8	IP
0B0H	B7	B6	B5	B4	B3	B2	B1	B0	P3
	EA			ES	ET1	EX1	ET0	EX0	
0A8H	AF	—	—	AC	AB	AA	A9	A8	IE
0A0H	A7	A6	A5	A4	A3	A2	A1	A0	P2
99H	Not Bit Addressable								SBUF
	SM0	SM1	SM2	REN	TB8	RB8	TI	RI	
98H	9F	9E	9D	9C	9B	9A	99	98	SCON
90H	97	96	95	94	93	92	91	90	P1
8DH	Not Bit Addressable								TH1
8CH	Not Bit Addressable								TH0
8BH	Not Bit Addressable								TL1
8AH	Not Bit Addressable								TL0
89H	Not Bit Addressable								TMOD
	TF1	TR1	TF0	TR0	IE1	IT1	IE0	IT0	
88H	8F	8E	8D	8C	8B	8A	89	88	TCON
87H	Not Bit Addressable								PCON
83H	Not Bit Addressable								DPH
82H	Not Bit Addressable								DPL
81H	Not Bit Addressable								SP
80H	87	86	85	84	83	82	81	80	P0

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INSTRUCTION LIST

List of Instruction Symbols

A	: Accumulator
AB	: Register pair
AC	: Auxiliary carry flag
B	: Arithmetic operation register
C	: Carry flag
DPTR	: Data pointer
PC	: Program counter
Rr	: Register indicator (r = 0 to 7)
SP	: Stack pointer
AND	: Logical product
OR	: Logical sum
XOR	: Exclusive-OR
+	: Addition
−	: Subtraction
X	: Multiplication
/	: Division
(X)	: Denotes the contents of X
((X))	: Denotes the contents of address determined by the contents of X
#	: Denotes the immediate data
@	: Denotes the indirect address
=	: Equality
≠	: Non-equality
←	: Substitution
→	: Substitution
—	: Negation
<	: Smaller than
>	: Larger than
bit address	: RAM and the special function register bit specifier address (b ₀ to b ₇)
code address	: Absolute address (A ₀ to A ₁₅)
data	: Immediate data (I ₀ to I ₇)
relative offset	: Relative jump address offset value (R ₀ to R ₇)
direct address	: RAM and the special function register byte specifier address (a ₀ to a ₇)

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MSM80C31F/MSM80C51F Instruction Codes

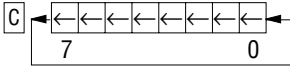
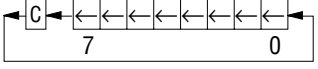
H \ L	0 0000	1 0001	2 0010	3 0011	4 0100	5 0101	6 0110	7 0111
0 0000	NOP	AJMP address 11 (Page 0)	LJMP address 16	RR A	INC A	INC direct	INC @R0	INC @R1
1 0001	JBC bit, rel	ACALL address 11 (Page 0)	LCALL address 16	RRC A	DEC A	DEC direct	DEC @R0	DEC @R1
2 0010	JB bit, rel	AJMP address 11 (Page 1)	RET	RL A	ADD A, #data	ADD A, direct	ADD A, @R0	ADD A, @R1
3 0011	JNB bit, rel	ACALL address 11 (Page 1)	RETI	RLC A	ADDC A, #data	ADDC A, direct	ADDC A, @R0	ADDC A, @R1
4 0100	JC rel	AJMP address 11 (Page 2)	ORL direct, A	ORL direct, #data	ORL A, #data	ORL A, direct	ORL A, @R0	ORL A, @R1
5 0101	JNC rel	ACALL address 11 (Page 2)	ANL direct, A	ANL direct, #data	ANL A, #data	ANL A, direct	ANL A, @R0	ANL A, @R1
6 0110	JZ rel	AJMP address 11 (Page 3)	XRL direct, A	XRL direct, #data	XRL A, #data	XRL A, direct	XRL A, @R0	XRL A, @R1
7 0111	JNZ rel	ACALL address 11 (Page 3)	ORL C, bit	JMP @A+DPTR	MOV A, #data	MOV direct #data	MOV @R0, #data	MOV @R1, #data
8 1000	SJMP rel	AJMP address 11 (Page 4)	ANL C, bit	MOVC A, @A+PC	DIV AB	MOV direct1, direct2	MOV direct, @R0	MOV direct, @R1
9 1001	MOV DPTR, #data 16	ACALL address 11 (Page 4)	MOV bit, C	MOVC A, @A+DPTR	SUBB A, #data	SUBB A, direct	SUBB A, @R0	SUBB A, direct
A 1010	ORL C, /bit	AJMP address 11 (Page 5)	MOV C, bit	INC DPTR	MUL AB		MOV @R0, direct	MOV @R1, direct
B 1011	ANL C, /bit	ACALL address 11 (Page 5)	CPL bit	CPL C	CJNE A, #data rel	CJNE A, direct, rel	CJNE @R0, #data, rel	CJNE @R1, #data, rel
C 1100	PUSH direct	AJMP address 11 (Page 6)	CLR bit	CLR C	SWAP A	XCH A, direct	XCH A, @R0	XCH A, @R1
D 1101	POP direct	ACALL address 11 (Page 6)	SETB bit	SETB C	DA A	DJNZ direct, rel	XCHD A, @R0	XCHD A, @R1
E 1110	MOVX A, @DPTR	AJMP address 11 (Page 7)	MOVX A, @R0	MOVX A, @R1	CLR A	MOV A, direct	MOV A, @R0	MOV A, @R1
F 1111	MOVX @DPTR, A	ACALL address 11 (Page 7)	MOVX @R0, A	MOVX @R1, A	CPL A	MOV direct, A	MOV @R0, A	MOV @R1, A

2BYTES		3BYTES
2CYCLES	MNEMONIC	4CYCLES

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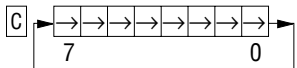
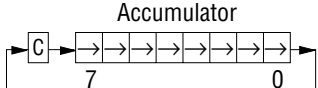
H \ L	8 1000	9 1001	A 1010	B 1011	C 1100	D 1101	E 1110	F 1111
0 0000	INC R0	INC R1	INC R2	INC R3	INC R4	INC R5	INC R6	INC R7
1 0001	DEC R0	DEC R1	DEC R2	DEC R3	DEC R4	DEC R5	DEC R6	DEC R7
2 0010	ADD A, R0	ADD A, R1	ADD A, R2	ADD A, R3	ADD A, R4	ADD A, R5	ADD A, R6	ADD A, R7
3 0011	ADDC A, R0	ADDC A, R1	ADDC A, R2	ADDC A, R3	ADDC A, R4	ADDC A, R5	ADDC A, R6	ADDC A, R7
4 0100	ORL A, R0	ORL A, R1	ORL A, R2	ORL A, R3	ORL A, R4	ORL A, R5	ORL A, R6	ORL A, R7
5 0101	ANL A, R0	ANL A, R1	ANL A, R2	ANL A, R3	ANL A, R4	ANL A, R5	ANL A, R6	ANL A, R7
6 0110	XRL A, R0	XRL A, R1	XRL A, R2	XRL A, R3	XRL A, R4	XRL A, R5	XRL A, R6	XRL A, R7
7 0111	MOV R0, #data	MOV R1, #data	MOV R2, #data	MOV R3, #data	MOV R4, #data	MOV R5, #data	MOV R6, #data	MOV R7, #data
8 1000	MOV direct, R0	MOV direct, R1	MOV direct, R2	MOV direct, R3	MOV direct, R4	MOV direct, R5	MOV direct, R6	MOV direct, R7
9 1001	SUBB A, R0	SUBB A, R1	SUBB A, R2	SUBB A, R3	SUBB A, R4	SUBB A, R5	SUBB A, R6	SUBB A, R7
A 1010	MOV R0, direct	MOV R1, direct	MOV R2, direct	MOV R3, direct	MOV R4, direct	MOV R5, direct	MOV R6, direct	MOV R7, direct
B 1011	CJNE R0, #data rel	CJNE R1, #data rel	CJNE R2, #data rel	CJNE R3, #data rel	CJNE R4, #data rel	CJNE R5, #data rel	CJNE R6, #data rel	CJNE R7, #data rel
C 1100	XCH A, R0	XCH A, R1	XCH A, R2	XCH A, R3	XCH A, R4	XCH A, R5	XCH A, R6	XCH A, R7
D 1101	DJNZ R0, rel	DJNZ R1, rel	DJNZ R2, rel	DJNZ R3, rel	DJNZ R4, rel	DJNE R5, rel	DJNE R6, rel	DJNE R7, rel
E 1110	MOV A, R0	MOV A, R1	MOV A, R2	MOV A, R3	MOV A, R4	MOV A, R5	MOV A, R6	MOV A, R7
F 1111	MOV R0, A	MOV R1, A	MOV R2, A	MOV R3, A	MOV R4, A	MOV R5, A	MOV R6, A	MOV R7, A

Instruction Set Details

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Arithmetic operation instructions	ADD A, Rr	0	0	1	0	1	r ₂	r ₁	r ₀	1	1	(AC), (0V), (C), (A) ← (A)+(Rr)
	ADD A, direct	0	0	1	0	0	1	0	1	2	1	(AC), (0V), (C), (A) ← (A)+(direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ADD A, @Rr	0	0	1	0	0	1	1	r ₀	1	1	(AC), (0V), (C), (A) ← (A)+((Rr))
	ADD A, #data	0	0	1	0	0	1	0	0	2	1	(AC), (0V), (C), (A) ← (A)+#data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	ADDC A, Rr	0	0	1	1	1	r ₂	r ₁	r ₀	1	1	(AC), (0V), (C), (A) ← (A)+(C)+(Rr)
	ADDC A, direct	0	0	1	1	0	1	0	1	2	1	(AC), (0V), (C), (A) ← (A)+(C)+(direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ADDC A, @Rr	0	0	1	1	0	1	1	r ₀	1	1	(AC), (0V), (C), (A) ← (A)+(C)+((Rr))
	ADDC A, #data	0	0	1	1	0	1	0	0	2	1	(AC), (0V), (C), (A) ← (A)+(C)+#data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	SUBB A, Rr	1	0	0	1	1	r ₂	r ₁	r ₀	1	1	(AC), (0V), (C), (A) ← (A)-((C))+((Rr))
	SUBB A, direct	1	0	0	1	0	1	0	1	2	1	(AC), (0V), (C), (A) ← (A)-((C)+(direct address))
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
Accumulation operation instructions	SUBB A, @Rr	1	0	0	1	0	1	1	r ₀	1	1	(AC), (0V), (C), (A) ← (A)-((C))+((Rr))
	SUBB A, #data	1	0	0	1	0	1	0	0	2	1	(AC), (0V), (C), (A) ← (A)-((C)+#data)
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MUL AB	1	0	1	0	0	1	0	0	1	4	(AB) ← (A) x (B)
	DIV AB	1	0	0	0	0	1	0	0	1	4	(A) quotient, (B) remainder ← (A)/(B)
	DA A	1	1	0	1	0	1	0	0	1	1	When the contents of accumulator bits 0 thru 3 are greater than 9, or when auxiliary carry (AC) is 1, 6 is added to bits 0 thru 3. Bits 4 thru 7 are then examined, and when bits 4thru 7 following compensation of lower bits 0 thru 3 is greater than 9, or when carry (C) is 1, 6 is added to bits 4 thru 7. As a result, the carry flag can be set, but cannot be cleared.
	CLR A	1	1	1	0	0	1	0	0	1	1	(A) ← 0
Accumulation operation instructions	CPL A	1	1	1	1	0	1	0	0	1	1	(A) ← (A)
	PL A	0	0	1	0	0	0	1	1	1	1	Accumulator 
	PL C	0	0	1	1	0	0	1	1	1	1	Accumulator 

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Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Accumulation operation instructions	RR A	0	0	0	0	0	0	1	1	1	1	
	RRC A	0	0	0	1	0	0	1	1	1	1	
	SWAP A	1	1	0	0	0	1	0	0	1	1	(A ₄₋₇) ↔ (A ₀₋₃)
Increment/decrement	INC A	0	0	0	0	0	1	0	0	1	1	(A) ← (A)+1
	INC Rr	0	0	0	0	1	r ₂	r ₁	r ₀	1	1	(Rr) ← (Rr)+1
	INC direct	0	0	0	0	0	1	0	1	2	1	(direct address) ← (direct address)+1
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	INC @Rr	0	0	0	0	0	1	1	r ₀	1	1	((Rr)) ← ((Rr))+1
	INC DPTR	1	0	1	0	0	0	1	1	1	2	(DPTR) ← (DPTR)+1
	DEC A	0	0	0	1	0	1	0	0	1	1	(A) ← (A)-1
	DEC Rr	0	0	0	1	1	r ₂	r ₁	r ₀	1	1	(Rr) ← (Rr)-1
	DEC direct	0	0	0	1	0	1	0	1	2	1	(direct address) ← (direct address)-1
Logical operation instructions		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	DEC @Rr	0	0	0	1	0	1	1	r ₀	1	1	((Rr)) ← ((Rr))-1
	ANL A, Rr	0	1	0	1	1	r ₂	r ₁	r ₀	1	1	(A) ← (A) AND (Rr)
	ANL A, direct	0	1	0	1	0	1	0	1	2	1	(A) ← (A) AND (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ANL A, @Rr	0	1	0	1	0	1	1	r ₀	1	1	(A) ← (A) AND ((Rr))
	ANL A, #data	0	1	0	1	0	1	0	0	2	1	(A) ← (A) AND #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	ANL direct, A	0	1	0	1	0	0	1	0	2	1	(direct address) ← (direct address) AND (A)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ANL direct, #data	0	1	0	1	0	0	1	1	3	2	(direct address) ← (direct address) AND #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	ORL A, Rr	0	1	0	0	1	r ₂	r ₁	r ₀	1	1	(A) ← (A) OR (Rr)
	ORL A, direct	0	1	0	0	0	1	0	1	2	1	(A) ← (A) OR (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ORL A, @Rr	0	1	0	0	0	1	1	r ₀	1	1	(A) ← (A) OR ((Rr))
	ORL A, #data	0	1	0	0	0	1	0	0	2	1	(A) ← (A) OR #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	ORL direct, A	0	1	0	0	0	0	1	0	2	1	(direct address) ← (direct address) OR (A)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			

Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Logical operation instructions	ORL direct, #data	0	1	0	0	0	0	1	1	3	2	(direct address) ← (direct address) OR #data
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	XRL A, Rr	0	1	1	0	1	r ₂	r ₁	r ₀	1	1	(A) ← (A) XOR (Rr)
	XRL A, direct	0	1	1	0	0	1	0	1	2	1	(A) ← (A) XOR (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
Immediate data setting instructions	XRL A, @Rr	0	1	1	0	0	1	1	r ₀	1	1	(A) ← (A) XOR ((Rr))
	XRL A, #data	0	1	1	0	0	1	0	0	2	1	(A) ← (A) XOR #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	XRL direct, A	0	1	1	0	0	0	1	0	2	1	(direct address) ← (direct address) XOR (A)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	XRL direct, #data	0	1	1	0	0	0	1	1	3	2	(direct address) ← (direct address) XOR #data
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
Carry flag operation instructions		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MOV A, #data	0	1	1	1	0	1	0	0	2	1	(A) ← #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MOV Rr, #data	0	1	1	1	1	r ₂	r ₁	r ₀	2	1	(Rr) ← #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MOV direct, #data	0	1	1	1	0	1	0	1	3	2	(direct address) ← #data
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MOV @Rr, #data	0	1	1	1	0	1	1	r ₀	2	1	(Rr) ← #data
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	MOV DPTR, #data 16	1	0	0	1	0	0	0	0	3	2	(DPTR) ← #data 16
		l ₁₅	l ₁₄	l ₁₃	l ₁₂	l ₁₁	l ₁₀	l ₉	l ₈			
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
	CLR C	1	1	0	0	0	0	1	1	1	1	(C) ← 0
	SETB C	1	1	0	1	0	0	1	1	1	1	(C) ← 1
	CPL C	1	0	1	1	0	0	1	1	1	1	(C) ← $\overline{(C)}$
	ANL C, bit	1	0	0	0	0	0	1	0	2	2	(C) ← (C) AND (bit address)
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	ANL C,/bit	1	0	1	1	0	0	0	0	2	2	(C) ← (C) AND $\overline{(\text{bit address})}$
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	ORL C, bit	0	1	1	1	0	0	1	0	2	2	(C) ← (C) OR (bit address)
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	ORL C,/bit	1	0	1	0	0	0	0	0	2	2	(C) ← (C) OR $\overline{(\text{bit address})}$
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			

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Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Carry flag operation instructions	MOV C, bit	1	0	1	0	0	0	1	0	2	1	(C) ← (bit address)
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	MOV bit, C	1	0	0	1	0	0	1	0	2	2	(bit address) ← (C)
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
Bit operation instructions	SETB bit	1	1	0	1	0	0	1	0	2	1	(bit address) ← 1
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	CLR bit	1	1	0	0	0	0	1	0	2	1	(bit address) ← 0
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
	CPL bit	1	0	1	1	0	0	1	0	2	1	(bit address) ← $\overline{(\text{bit address})}$
		b ₇	b ₆	b ₅	b ₄	b ₃	b ₂	b ₁	b ₀			
Data transfer instructions	MOV A, Rr	1	1	1	0	1	r ₂	r ₁	r ₀	1	1	(A) ← (Rr)
	MOV A, direct	1	1	1	0	0	1	0	1	2	1	(A) ← (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	MOV A, @Rr	1	1	1	0	0	1	1	r ₀	1	1	(A) ← ((Rr))
	MOV Rr, A	1	1	1	1	1	r ₂	r ₁	r ₀	1	1	(Rr) ← (A)
	MOV Rr, direct	1	0	1	0	1	r ₂	r ₁	r ₀	2	2	(Rr) ← (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	MOV direct, A	1	1	1	1	0	1	0	1	2	1	(direct address) ← (A)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	MOV direct, Rr	1	0	0	0	1	r ₂	r ₁	r ₀	2	2	(direct address) ← (Rr)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	MOV direct 1, direct 2	1	0	0	0	0	1	1	r ₀	3	2	(direct address 1) ← (direct address 2)
		a ₇ ²	a ₆ ²	a ₅ ²	a ₄ ²	a ₃ ²	a ₂ ²	a ₁ ²	a ₀ ²			
		a ₇ ¹	a ₆ ¹	a ₅ ¹	a ₄ ¹	a ₃ ¹	a ₂ ¹	a ₁ ¹	a ₀ ¹			
	MOV @Rr, A	1	1	1	1	0	1	1	r ₀	1	1	((Rr)) ← (A)
	MOV @Rr, direct	1	0	1	0	0	1	1	r ₀	2	2	((Rr)) ← (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
Constant code instructions	MOVC A, @A+DPTR	1	0	0	1	0	0	1	1	1	2	(A) ← ((A)+(DPTR))
	MOVC A, @A+PC	1	0	0	0	0	0	1	1	1	2	(PC) ← (PC+1) (A) ← ((A)+(PC))
Data exchange instructions	XCH A, Rr	1	1	0	0	1	r ₂	r ₁	r ₀	1	1	(A) ↔ (Rr)
	XCH A, direct	1	1	0	0	0	1	0	1	2	2	(A) ↔ (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	XCH A, @Rr	1	1	0	0	0	1	1	r ₀	1	1	(A) ↔ ((Rr))
	XCHD A, @Rr	1	1	0	1	0	1	1	r ₀	1	1	(A ₀₋₃) ↔ ((Rr ₀₋₃))

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Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Subroutine instructions	PUSH direct	1	1	0	0	0	0	0	0	2	2	(SP) ← (SP)+1 ((SP)) ← (direct address)
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	POP direct	1	1	0	1	0	0	0	0	2	2	(direct address) ← ((SP)) (SP) ← (SP)-1
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
	ACALL addr 11	A ₁₀	A ₉	A ₈	1	0	0	0	1	2	2	(PC) ← (PC)+2 (SP) ← (SP)+1 ((SP)) ← (PC ₀ - 7) (SP) ← (SP)+1 ((SP)) ← (PC ₈ - 15) (PC ₀ - 10) ← A ₀ - 10
		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀			
Subroutine instructions	LCALL addr 16	0	0	0	1	0	0	1	0	3	2	(PC) ← (PC)+3 (SP) ← (SP)+1 ((SP)) ← (PC ₀ - 7) (SP) ← (SP)+1 ((SP)) ← (PC ₈ - 15) (PC ₀ - 10) ← A ₀ - 10
		A ₁₅	A ₁₄	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A ₉	A ₈			
		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀			
	RET	0	0	1	0	0	0	1	0	1	2	(PC ₈ - 15) ← ((SP)) (SP) ← (SP)-1 (PC ₀ - 7) ← ((SP)) (SP) ← (SP)-1
	RETI	0	0	1	1	0	0	1	0	1	2	(PC ₈ - 15) ← ((SP)) (SP) ← (SP)-1 (PC ₀ - 7) ← ((SP)) (SP) ← (SP)-1
Jump instructions	AJMP addr 11	A ₁₀	A ₉	A ₈	0	0	0	0	1	2	2	(PC) ← (PC)+2 (PC ₀ - 10) ← A ₀ - 10
		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀			
	LJMP addr 16	0	0	0	0	0	0	1	0	3	2	(PC ₀ - 15) ← A ₀ - 15
		A ₁₅	A ₁₄	A ₁₃	A ₁₂	A ₁₁	A ₁₀	A ₉	A ₈			
Jump instructions		A ₇	A ₆	A ₅	A ₄	A ₃	A ₂	A ₁	A ₀			
	SJMP rel	1	0	0	0	0	0	0	0	2	2	(PC) ← (PC)+3 (SP) ← (SP)+1
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
	JMP @A+ DPTR	0	1	1	1	0	0	1	1	1	2	(PC) ← (A)+(DPTR)

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Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Branch instructions	CJNE A, direct, rel	1	0	1	1	0	1	0	1	3	2	(PC) ← (PC)+3 IF (A)≠(direct address) THEN (PC) ← (PC)+relative offset IF (A)<(direct address) THEN (C) ← 1 ELSE (C) ← 0
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
	CJNE A, #data, rel	1	0	1	1	0	1	0	0	3	2	(PC) ← (PC)+3 IF (A)≠ #data THEN (PC) ← (PC)+relative offset IF (A)< #data THEN (C) ← 1 ELSE (C) ← 0
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
Branch instructions	CJNE Rr, #data, rel	1	0	1	1	1	r ₂	r ₁	r ₀	3	2	(PC) ← (PC)+3 IF ((Rr))≠ #data THEN (PC) ← (PC)+relative offset IF (Rr)< #data THEN (C) ← 1 ELSE (C) ← 0
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
	CJNE @Rr, #data, rel	1	0	1	1	0	1	1	r ₀	3	2	(PC) ← (PC)+3 IF ((Rr))≠ #data THEN (PC) ← (PC)+relative offset IF ((Rr))< #data THEN (C) ← 1 ELSE (C) ← 0
		l ₇	l ₆	l ₅	l ₄	l ₃	l ₂	l ₁	l ₀			
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
Branch instructions	DJNZ Rr, rel	1	1	0	1	1	r ₂	r ₁	r ₀	2	2	(PC) ← (PC)+2 (Rr) ← (Rr)-1 IF (Rr)< 0 THEN (PC) ← (PC)+relative offset
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			
Branch instructions	DJNZ direct, rel	1	1	0	1	0	1	0	1	3	2	(PC) ← (PC)+3 (direct address) ← (direct address)-1 IF (direct address)≠ 0 THEN (PC) ← (PC)+relative offset
		a ₇	a ₆	a ₅	a ₄	a ₃	a ₂	a ₁	a ₀			
		R ₇	R ₆	R ₅	R ₄	R ₃	R ₂	R ₁	R ₀			

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Instruction Set Details (continued)

Type	Mnemonic	Instruction code								Bytes	Cycles	Description
		D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀			
Branch instructions	JZ rel	0	1	1	0	0	0	0	0	2	2	(PC) ← (PC)+2 IF (A) = 0 THEN (PC) ← (PC)+relative offset
	JNZ rel	0	1	1	1	0	0	0	0	2	2	(PC) ← (PC)+2 IF (A) ≠ 0 THEN (PC) ← (PC)+relative offset
	JC rel	0	1	0	0	0	0	0	0	2	2	(PC) ← (PC)+2 IF (C) = 1 THEN (PC) ← (PC)+relative offset
	JNC rel	0	1	0	1	0	0	0	0	2	2	(PC) ← (PC)+2 IF (C) = 0 THEN (PC) ← (PC)+relative offset
	JB bit, rel	0	0	1	0	0	0	0	0	3	2	(PC) ← (PC)+3 IF (bit address) = 1 THEN (PC) ← (PC)+relative offset
	JNB bit, rel	0	0	1	1	0	0	0	0	3	2	(PC) ← (PC)+3 IF (bit address) = 0 THEN (PC) ← (PC)+relative offset
	JBC bit, rel	0	0	0	1	0	0	0	0	3	2	(PC) ← (PC)+3 IF (bit address) = 1 THEN (bit address) ← 0 (PC) ← (PC)+relative offset
External memory instructions	MOVX A, @Rr	1	1	1	0	0	0	0	r ₀	1	2	(A) ← ((Rr)) EXTERNAL RAM
	MOVX A, @DPTR	1	1	1	0	0	0	0	0	1	2	(A) ← ((DPTR)) EXTERNAL RAM
	MOVX @Rr, A	1	1	1	1	0	0	1	r ₀	1	2	(Rr) ← (A) EXTERNAL RAM
	MOVX @DPTR, A	1	1	1	1	0	0	0	0	1	2	((DPTR)) ← (A) EXTERNAL RAM
Other instructions	NOP	0	0	0	0	0	0	0	0	1	1	(PC) ← (PC)+1

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ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rating	Unit
Supply Voltage	V_{CC}	$T_a = 25^{\circ}\text{C}$	-0.5 to +7.0	V
Voltage from Any Pin to V_{SS}	V_I	$T_a = 25^{\circ}\text{C}$	-0.5 to $V_{CC} + 7.0$	V
Storage Temperature	T_{STG}	—	-55 to +150	$^{\circ}\text{C}$

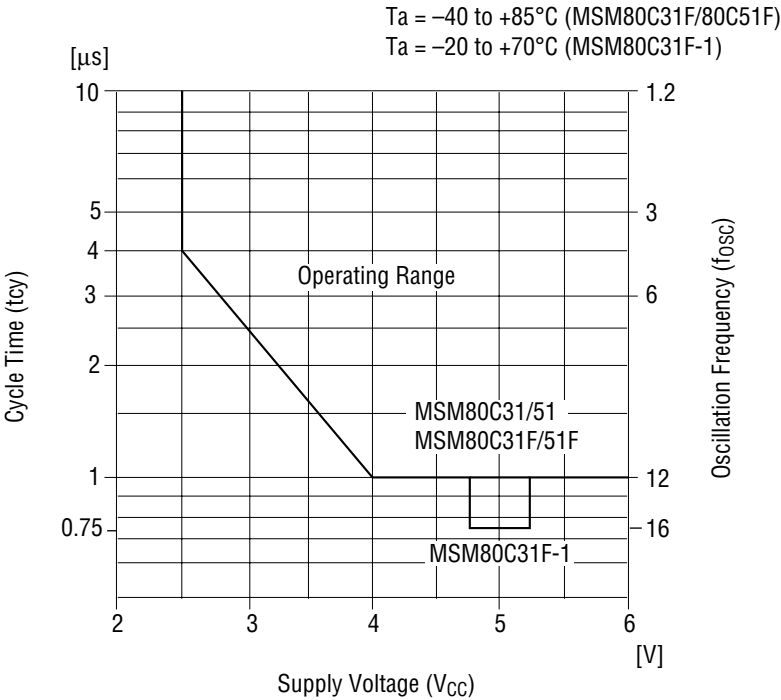
OPERATING RANGE

Parameter	Symbol	Condition	Range	Unit
Supply Voltage	V_{CC}	See figure below	2.5 to 6 *1	V
Memory Retention Voltage	V_{CC}	$f_{osc} = \text{Oscillation stop}$	2 to 6	V
Oscillation Frequency	f_{osc}	See figure below	DC to 16 *2	MHz
Ambient Temperature	T_a	MSM80C31F/51F	-40 to +85	$^{\circ}\text{C}$
		MSM80C31F-1	-20 to +70	

*1 DC & AC characteristics in the range of $2.5\text{ V} \leq V_{CC} < 4\text{ V}$ will be specified by DC & AC Characteristics 2.

*2 Specify MSM80C31F-1 when using MSM80C31F at 12 MHz to 16 MHz.

GUARANTEED OPERATING RANGE



[查询"MSM80C51F"供应商](#)**ELECTRICAL CHARACTERISTICS****DC Characteristics 1**

(MSM80C31F/51F $V_{CC} = 5\text{ V} \pm 20\%$, $V_{SS} = 0\text{ V}$, $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$)
 (MSM80C31F-1/51F-1 $V_{CC} = 5\text{ V} \pm 5\%$, $V_{SS} = 0\text{ V}$, $T_a = -20^\circ\text{C}$ to $+70^\circ\text{C}$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	Measuring circuit
Low Input Voltage	V_{IL}	—	-0.5	—	$0.2 V_{CC} - 0.1$	V	1
High Input Voltage	V_{IH}	Except XTAL1, RESET and $\overline{EA}$	$0.2 V_{CC} + 0.9$	—	$V_{CC} + 0.5$	V	
High Input Voltage	V_{IH1}	XTAL1, RESET and $\overline{EA}$	$0.7 V_{CC}$	—	$V_{CC} + 0.5$	V	
Low Output Voltage (Port 1, 2 and 3)	V_{OL}	$I_{OL} = 1.6\text{ mA}$	—	—	0.45	V	
Low Output Voltage (Port 0, ALE and $\overline{PSEN}$)	V_{OL1}	$I_{OL} = 3.2\text{ mA}$	—	—	0.45	V	
High Output Voltage (Port 1, 2 and 3)	V_{OH}	$I_{OH} = -60\text{ }\mu\text{A}$ $V_{CC} = 5\text{ V} \pm 10\%$	2.4	—	—	V	
		$I_{OH} = -30\text{ }\mu\text{A}$	$0.75 V_{CC}$	—	—	V	
		$I_{OH} = -10\text{ }\mu\text{A}$	$0.9 V_{CC}$	—	—	V	
High Output Voltage (Port 0, ALE and $\overline{PSEN}$)	V_{OH1}	$I_{OH} = -400\text{ }\mu\text{A}$ $V_{CC} = 5\text{ V} \pm 10\%$	2.4	—	—	V	
		$I_{OH} = -150\text{ }\mu\text{A}$	$0.75 V_{CC}$	—	—	V	
		$I_{OH} = -40\text{ }\mu\text{A}$	$0.9 V_{CC}$	—	—	V	
Output Current at Low Input/ High Output Power Supply	I_{IL} / I_{OH}	$V_I = 0.45\text{ V}$ $V_O = 0.45\text{ V}$	-10	—	-200	μA	2
Output Current (Port 1, 2 and 3) at transition from H to L	I_{TL}	$V_{IL} = 2.0\text{ V}$	—	—	-500	μA	
Input Leakage Current (Floating Port 0 and $\overline{EA}$)	I_{LI}	$V_{SS} < V_I < V_{CC}$	—	—	± 10	μA	3
RESET Pull-down Resistor	R_{RST}	—	20	40	125	$\text{k}\Omega$	2
Input Pin Capacitor	C_{IO}	$T_a = 25^\circ\text{C}$, $f = 1\text{ MHz}$ 5 V (except XTAL1)	—	—	10	pF	—
Power Down Current	I_{PD}	$V_{CC} = 2\text{ V}$	—	1	50	μA	4

DC Characteristics 2

(V_{CC} = 2.5 to 4.0 V, V_{SS} = 0 V, Ta = -40 to +85°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	Measuring circuit
Low Input Voltage	V _{IL}	—	-0.5	—	0.25V _{CC} - 0.1	V	1
High Input Voltage	V _{IH}	Except XTAL1, RESET and $\overline{EA}$	0.25V _{CC} + 0.9	—	V _{CC} + 0.5	V	
High Input Voltage	V _{IH1}	XTAL1, RESET and $\overline{EA}$	0.6V _{CC} + 0.6	—	V _{CC} + 0.5	V	
Low Output Voltage (Port 1, 2 and 3)	V _{OL}	I _{OL} = 10 μA	—	—	0.1	V	
Low Output Voltage (Port 0, ALE and $\overline{PSEN}$)	V _{OL1}	I _{OL} = 20 μA	—	—	0.1	V	
High Output Voltage (Port 1, 2 and 3)	V _{OH}	I _{OH} = -5 μA	0.75 V _{CC}	—	—	V	
High Output Voltage (Port 0, ALE and $\overline{PSEN}$)	V _{OH1}	I _{OH} = -20 μA	0.75 V _{CC}	—	—	V	2
Output Current at Low Input/ High Output Power Supply	I _{IL} / I _{OH}	$V_I = 0.1 \text{ V}$ $V_O = 0.1 \text{ V}$	—	—	-100	μA	
Output Current (Port 1, 2 and 3) at transition from H to L	I _{TL}	V _{IL} = 1.9 V	—	—	-300	μA	3
Input Leakage Current (Floating Port 0 and $\overline{EA}$)	I _{LI}	V _{SS} < V _I < V _{CC}	—	—	±10	μA	
RESET Pull-down Resistor	R _{RST}	—	20	40	125	kΩ	2
Input Pin Capacitor	C _{IO}	Ta = 25°C, f = 1 MHz 5 V (except XTAL1)	—	—	10	pF	—
Power Down Current	I _{PD}	—	—	1	10	μA	4

[查询"MSM80C51F"供应商](#)**Maximum operating power supply I_{CC} [mA]**

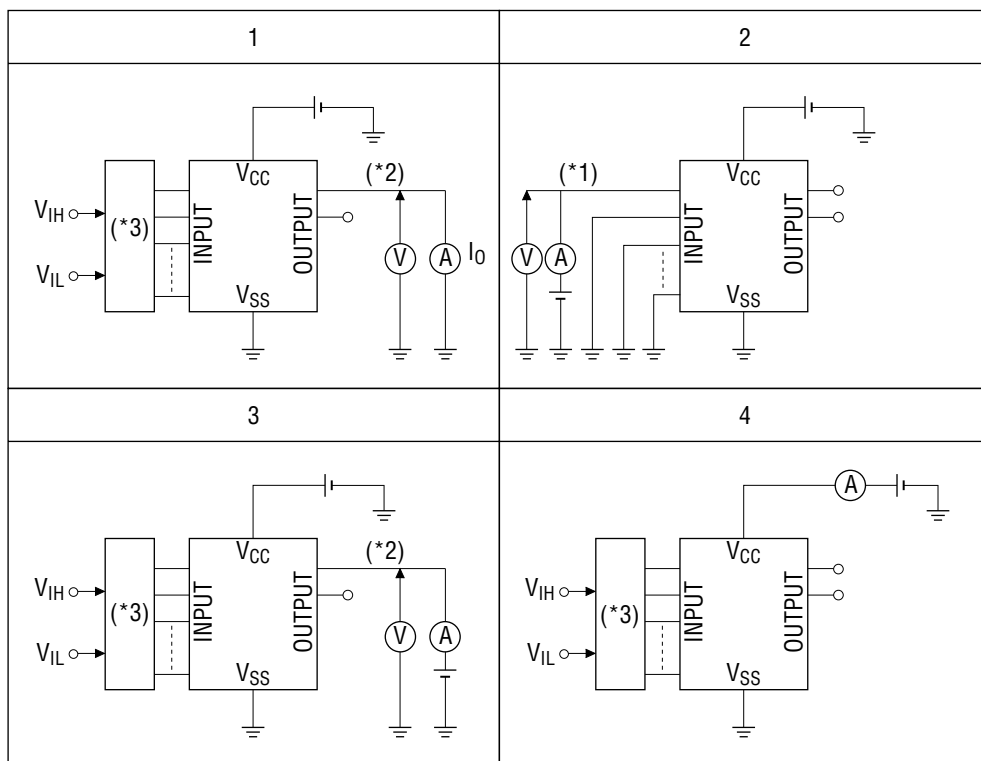
V_{CC}	2.5 V	3.0 V	4.0 V
Freq			
0.5 MHz	0.7	0.9	1.6
3.0 MHz	1.9	2.4	4.3
8 MHz	—	—	8.3
12 MHz	—	—	12.0

Maximum IDLE power supply I_{CC} [mA]

V_{CC}	2.5 V	3.0 V	4.0 V
Freq			
0.5 MHz	0.3	0.4	0.6
3.0 MHz	0.6	0.8	1.2
8 MHz	—	—	2.2
12 MHz	—	—	3.1

[查询"MSM80C51F"供应商](#)

Measuring Circuit



*1 Repeated for specified input pin.

*2 Repeated for specified output pin.

*3 Logic input for specified condition.

[查询"MSM80C51F"供应商](#)**External Program Memory Access AC Characteristics 1**

($V_{CC} = 5\text{ V} \pm 20\%$, $V_{SS} = 0\text{ V}$, $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$; Load Capacitance for Port 0, ALE, and $\overline{\text{PSEN}}$ = 100 pF; Load Capacitance for all other outputs = 80 pF)

Parameter	Symbol	12 MHz Clock		Variable Clock See Guaranteed Operating Range		Unit
		Min.	Max.	Min.	Max.	
XTAL1, XTAL2 Oscillation Cycle	t_{CLCL}	—	—	83.3	—	ns
ALE Signal Width	t_{LHLL}	126	—	$2t_{\text{CLCL}} - 40$	—	ns
Address Setup Time (to ALE Falling Edge)	t_{AVLL}	43	—	$1t_{\text{CLCL}} - 40$	—	ns
Address Hold Time (from ALE Falling Edge)	t_{LLAX}	48	—	$1t_{\text{CLCL}} - 35$	—	ns
Instruction Data Read Time (from ALE Falling Edge)	t_{LLIV}	—	233	—	$4t_{\text{CLCL}} - 100$	ns
From ALE Falling Edge to $\overline{\text{PSEN}}$ Falling Edge	t_{LLPL}	58	—	$1t_{\text{CLCL}} - 25$	—	ns
$\overline{\text{PSEN}}$ Signal Width	t_{PLPH}	215	—	$3t_{\text{CLCL}} - 35$	—	ns
Instruction Data Read Time (from $\overline{\text{PSEN}}$ Falling Edge)	t_{PLIV}	—	145	—	$3t_{\text{CLCL}} - 105$	ns
Instruction Data Hold Time (from $\overline{\text{PSEN}}$ Rising Edge)	t_{PXIX}	0	—	0	—	ns
Bus Floating Time after Instruction Data Read (from $\overline{\text{PSEN}}$ Rising Edge)	t_{PXIZ}	—	63	—	$1t_{\text{CLCL}} - 20$	ns
Address Output Time from $\overline{\text{PSEN}}$ Rising Edge	t_{PXAV}	75	—	$1t_{\text{CLCL}} - 8$	—	ns
Instruction Data Read Time (from Address Output)	t_{AVIV}	—	312	—	$5t_{\text{CLCL}} - 105$	ns
Bus Floating Time (Address Float from $\overline{\text{PSEN}}$ Falling Edge)	t_{PLAZ}	—	0	—	0	ns

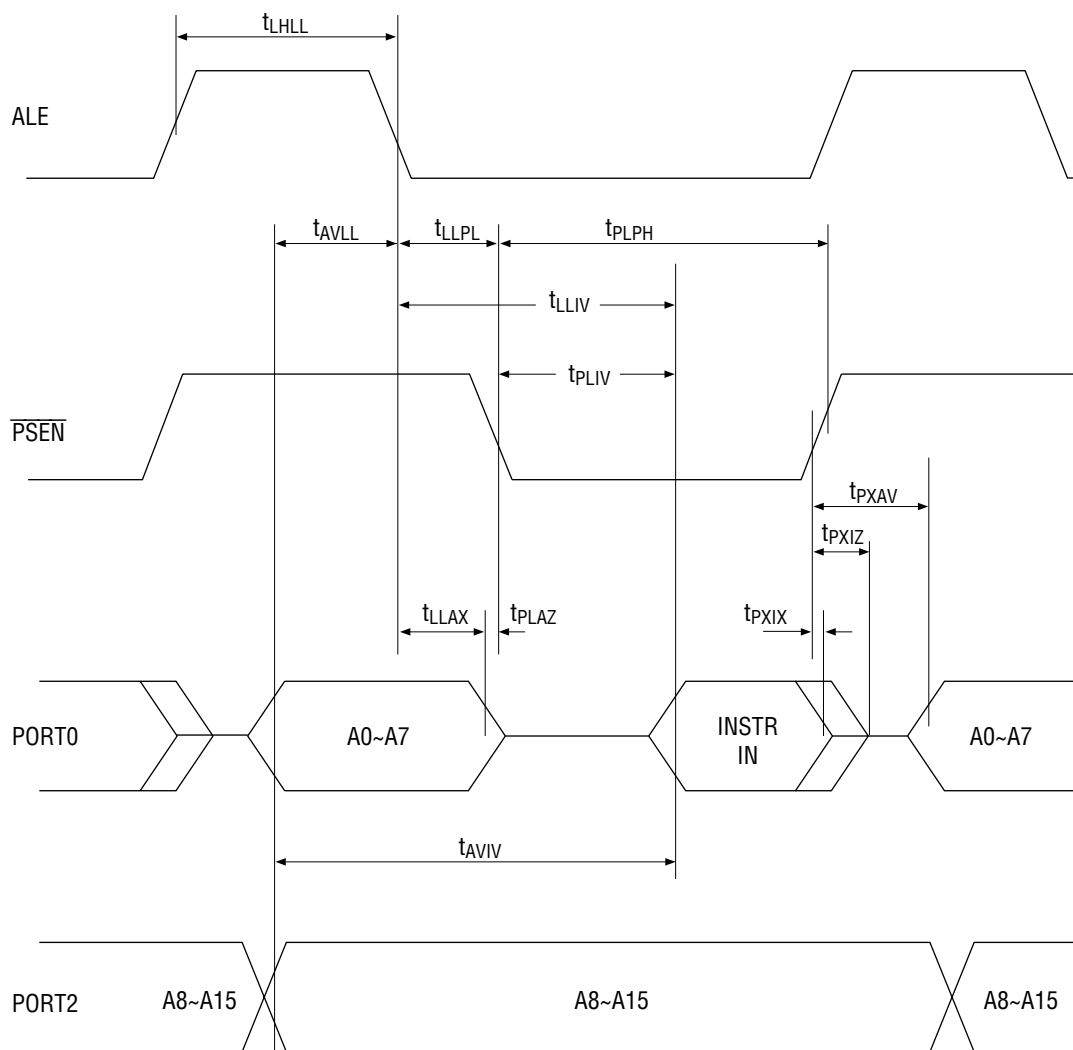
[查询"MSM80C51F"供应商](#)**External Program Memory Access AC Characteristics 2**

($V_{CC} = 2.5$ to 4.0 V, $V_{SS} = 0$ V, $T_a = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$; Load Capacitance for Port 0, ALE, and $\overline{\text{PSEN}}$ = 100 pF ; Load Capacitance for all other outputs = 80 pF)

Parameter	Symbol	12 MHz Clock		Variable Clock See Guaranteed Operating Range		Unit
		Min.	Max.	Min.	Max.	
XTAL1, XTAL2 Oscillation Cycle	t_{CLCL}	—	—	83.3	—	ns
ALE Signal Width	t_{LHLL}	126	—	$2t_{\text{CLCL}} - 40$	—	ns
Adderss Setup Time (to ALE Falling Edge)	t_{AVLL}	43	—	$1t_{\text{CLCL}} - 40$	—	ns
Adderss Hold Time (from ALE Falling Edge)	t_{LLAX}	48	—	$1t_{\text{CLCL}} - 35$	—	ns
Instruction Data Read Time (from ALE Falling Edge)	t_{LLIV}	—	233	—	$4t_{\text{CLCL}} - 100$	ns
From ALE Falling Edge to $\overline{\text{PSEN}}$ Falling Edge	t_{LLPL}	58	—	$1t_{\text{CLCL}} - 25$	—	ns
$\overline{\text{PSEN}}$ Signal Width	t_{PLPH}	215	—	$3t_{\text{CLCL}} - 35$	—	ns
Instruction Data Read Time (from $\overline{\text{PSEN}}$ Falling Edge)	t_{PLIV}	—	145	—	$3t_{\text{CLCL}} - 105$	ns
Instruction Data Hold Time (from $\overline{\text{PSEN}}$ Rising Edge)	t_{PXIX}	0	—	0	—	ns
Bus Floating Time after Instruction Data Read (from $\overline{\text{PSEN}}$ Rising Edge)	t_{PXIZ}	—	63	—	$1t_{\text{CLCL}} - 20$	ns
Address Output Time from $\overline{\text{PSEN}}$ Rising Edge	t_{PXAV}	75	—	$1t_{\text{CLCL}} - 8$	—	ns
Instruction Data Read Time (from Address Output)	t_{AVIV}	—	312	—	$5t_{\text{CLCL}} - 105$	ns
Bus Floating Time (Address Float from $\overline{\text{PSEN}}$ Falling Edge)	t_{PLAZ}	—	0	—	0	ns

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External Program Memory Read Cycle



[查询"MSM80C51F"供应商](#)**External Data Memory Access AC Characteristics 1**

($V_{CC} = 5\text{ V} \pm 20\%$, $V_{SS} = 0\text{ V}$, $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$; load capacitance for Port 0, ALE, and $\overline{\text{PSEN}} = 100\text{ pF}$; load capacitance for all other outputs = 80 pF)

Parameter	Symbol	12 MHz Clock		Variable Clock See Guaranteed Operating Range		Unit
		Min.	Max.	Min.	Max.	
XTAL1, XTAL2 Oscillation Cycle	t_{CLCL}	—	—	62.5	—	ns
ALE Single Width	t_{LHLL}	126	—	$2t_{\text{CLCL}} - 40$	—	ns
Address Setup Time (to ALE Falling Edge)	t_{AVLL}	43	—	$t_{\text{CLCL}} - 40$	—	ns
Address Hold Time (from ALE Falling Edge)	t_{LLAX}	48	—	$t_{\text{CLCL}} - 35$	—	ns
$\overline{\text{RD}}$ Single Width	t_{RLRH}	400	—	$6t_{\text{CLCL}} - 100$	—	ns
$\overline{\text{WR}}$ Single Width	t_{WLWH}	400	—	$6t_{\text{CLCL}} - 100$	—	ns
RAM Data Read Time (from $\overline{\text{RD}}$ Single Falling Edge)	t_{RLDV}	—	251	—	$5t_{\text{CLCL}} - 165$	ns
RAM Data Read Hold Time (from $\overline{\text{RD}}$ Single Rising Edge)	t_{RHDX}	0	—	0	—	ns
Data Bus Floating Time (from $\overline{\text{RD}}$ Single Rising Edge)	t_{RHDZ}	—	96	—	$2t_{\text{CLCL}} - 70$	ns
RAM Data Read Time (from $\overline{\text{ALE}}$ Single Falling Edge)	t_{LLDV}	—	516	—	$8t_{\text{CLCL}} - 150$	ns
RAM Data Read Time (from Address Output)	t_{AVDV}	—	585	—	$9t_{\text{CLCL}} - 165$	ns
$\overline{\text{RD}}/\overline{\text{WR}}$ Output Time from ALE Falling Edge	t_{LLWL}	200	300	$3t_{\text{CLCL}} - 50$	$3t_{\text{CLCL}} + 50$	ns
$\overline{\text{RD}}/\overline{\text{WR}}$ Output Time from Address Output	t_{AVWL}	203	—	$4t_{\text{CLCL}} - 130$	—	ns
$\overline{\text{RD}}$ Output Time from Data Output	t_{QVWX}	23	—	$t_{\text{CLCL}} - 60$	—	ns
Time from Data Output to $\overline{\text{WR}}$ Rising Edge	t_{QVWH}	433	—	$7t_{\text{CLCL}} - 150$	—	ns
Data Hold Time ($\overline{\text{WR}}$ Rising Edge)	t_{WHQX}	33	—	$t_{\text{CLCL}} - 50$	—	ns
Time from $\overline{\text{RD}}$ Output to Address Float	t_{RLAZ}	—	0	—	0	ns
Time from $\overline{\text{RD}}/\overline{\text{WR}}$ Rising Edge to ALE Rising Edge	t_{WHLH}	43	133	$t_{\text{CLCL}} - 40$	$t_{\text{CLCL}} + 50$	ns

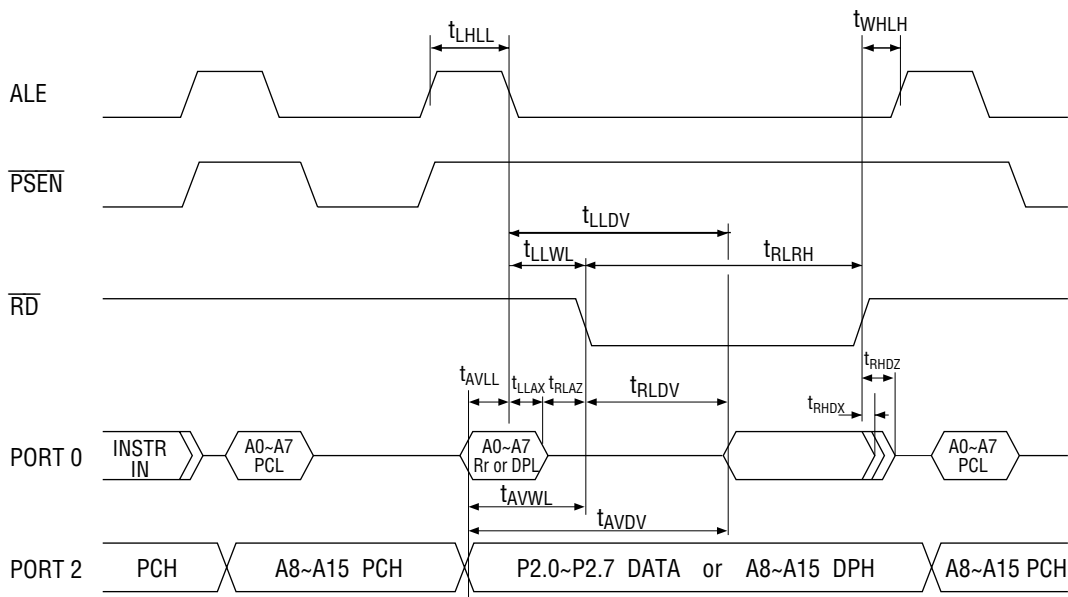
[查询"MSM80C51F"供应商](#)**External Data Memory Access AC Characteristics 2**

($V_{CC} = 2.5$ to 4.0 V, $V_{SS} = 0$ V, $T_a = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$; load capacitance for Port 0, ALE, and $\overline{\text{PSEN}} = 100$ pF; load capacitance for all other outputs = 80 pF)

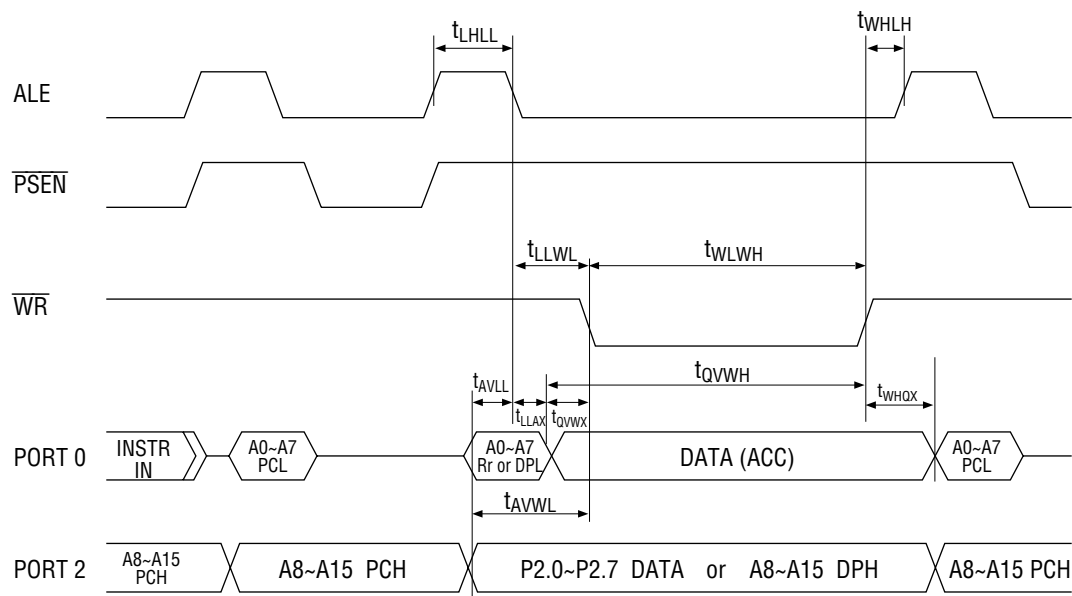
Parameter	Symbol	12 MHz Clock		Variable Clock See Guaranteed Operating Range		Unit
		Min.	Max.	Min.	Max.	
XTAL1, XTAL2 Oscillation Cycle	t_{CLCL}	—	—	62.5	—	ns
ALE Single Width	t_{LHLL}	126	—	$2t_{\text{CLCL}} - 40$	—	ns
Adderss Setup Time (to ALE Falling Edge)	t_{AVLL}	43	—	$1t_{\text{CLCL}} - 40$	—	ns
Adderss Hold Time (from ALE Falling Edge)	t_{LLAX}	48	—	$1t_{\text{CLCL}} - 35$	—	ns
$\overline{\text{RD}}$ Single Width	t_{RLRH}	400	—	$6t_{\text{CLCL}} - 100$	—	ns
$\overline{\text{WR}}$ Single Width	t_{WLWH}	400	—	$6t_{\text{CLCL}} - 100$	—	ns
RAM Data Read Time (from $\overline{\text{RD}}$ Single Falling Edge)	t_{RLDV}	—	251	—	$5t_{\text{CLCL}} - 165$	ns
RAM Data Read Hold Time (from $\overline{\text{RD}}$ Single Rising Edge)	t_{RHDX}	0	—	0	—	ns
Data Bus Floating Time (from $\overline{\text{RD}}$ Single Rising Edge)	t_{RHDZ}	—	96	—	$2t_{\text{CLCL}} - 70$	ns
RAM Data Read Time (from $\overline{\text{ALE}}$ Single Falling Edge)	t_{LLDV}	—	516	—	$8t_{\text{CLCL}} - 150$	ns
RAM Data Read Time (from Address Output)	t_{AVDV}	—	585	—	$9t_{\text{CLCL}} - 165$	ns
$\overline{\text{RD}}/\overline{\text{WR}}$ Output Time from ALE Falling Edge	t_{LLWL}	150	300	$3t_{\text{CLCL}} - 100$	$3t_{\text{CLCL}} + 50$	ns
$\overline{\text{RD}}/\overline{\text{WR}}$ Output Time from Address Output	t_{AVWL}	203	—	$4t_{\text{CLCL}} - 130$	—	ns
$\overline{\text{RD}}$ Output Time from Data Output	t_{QVWX}	23	—	$1t_{\text{CLCL}} - 60$	—	ns
Time from Data Output to $\overline{\text{WR}}$ Rising Edge	t_{QVWH}	433	—	$7t_{\text{CLCL}} - 150$	—	ns
Data Hold Time ($\overline{\text{WR}}$ Rising Edge)	t_{WHQX}	33	—	$1t_{\text{CLCL}} - 50$	—	ns
Time from $\overline{\text{RD}}$ Output to Address Float	t_{RLAZ}	—	0	—	0	ns
Time from $\overline{\text{RD}}/\overline{\text{WR}}$ Rising Edge to ALE Rising Edge	t_{WHLH}	43	183	$1t_{\text{CLCL}} - 40$	$1t_{\text{CLCL}} + 100$	ns

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External Data Memory Read Cycle



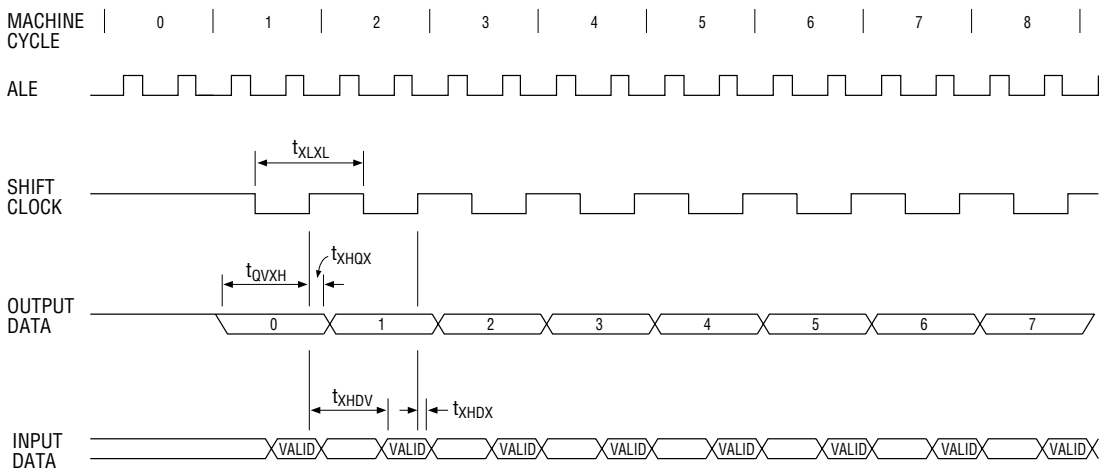
External Data Memory Write Cycle



Serial Port Timing (I/O Expansion Mode) AC Characteristics 1

(Ta = -40°C to +85°C ; V_{CC} = 5 V ±20% ; V_{SS} = 0 V)

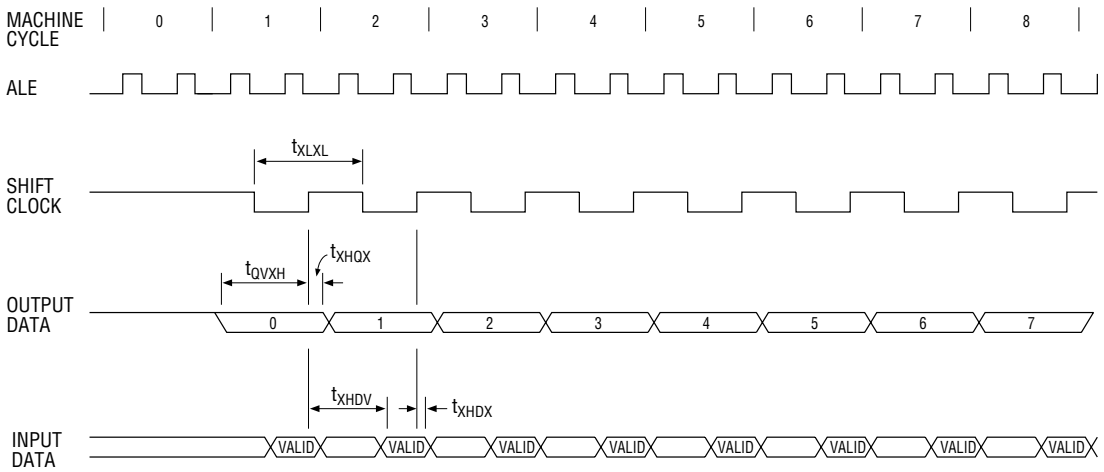
Parameter	Symbol	Min.	Max.	Unit
Serial port clock cycle time	t _{XLXL}	12t _{CLCL}	—	ns
Output data setup to clock rising edge	t _{QVXH}	10t _{CLCL} - 133	—	ns
Output data hold after clock rising edge	t _{XHQX}	2t _{CLCL} - 117	—	ns
Input data hold after clock rising edge	t _{XHDX}	0	—	ns
Clock rising edge to input data valid	t _{XHDV}	—	10t _{CLCL} - 133	ns



Serial Port Timing (I/O Expansion Mode) AC Characteristics 2

(Ta = -40°C to +85°C ; V_{CC} = 2.5 to 4.0 V ; V_{SS} = 0 V)

Parameter	Symbol	Min.	Max.	Unit
Serial port clock cycle time	t _{XLXL}	12t _{CLCL}	—	ns
Output data setup to clock rising edge	t _{QVXH}	10t _{CLCL} - 133	—	ns
Output data hold after clock rising edge	t _{XHQX}	2t _{CLCL} - 117	—	ns
Input data hold after clock rising edge	t _{XHDX}	0	—	ns
Clock rising edge to input data valid	t _{XHDV}	—	10t _{CLCL} - 133	ns



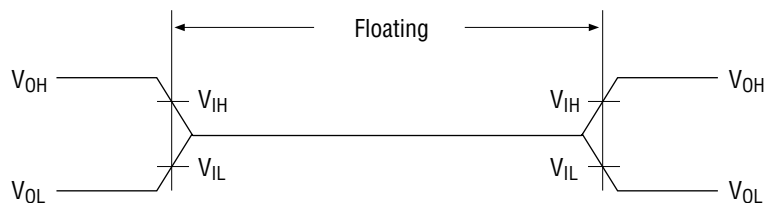
AC Characteristics Measuring Conditions

Input/output signal



- * The input signals in AC test mode are either V_{OH} (logic "1") or V_{OL} (logic "0") input signals where logic "1" corresponds to a CPU output signal waveform measuring point in excess of V_{IH} , and logic "0" to a point below V_{IL} .

Floating

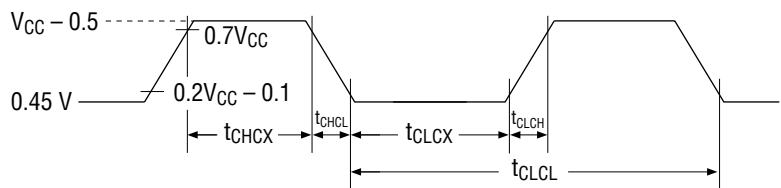


- * The port 0 floating interval is measured from the time the port 0 pin voltage drops below V_{IH} after sinking to GND at 2.4 mA when switching to floating status from a "1" output, and from the time the port 0 pin voltage exceeds V_{IL} after connecting to a 400 μ A source when switching to floating status from a "0" output.

XTAL1 External Clock Input Waveform Conditions

Parameter	Symbol	Variable Clock		
		See Guaranteed Operating Range		
		Min.	Max.	Unit
External Clock Frequency	$1/t_{CLCL}$	DC	16	MHz
High Time	t_{CHCX}	20	—	ns
Low Time	t_{CLCX}	20	—	ns
Rise Time	t_{CLCH}	—	20	ns
Fall Time	t_{CHCL}	—	20	ns

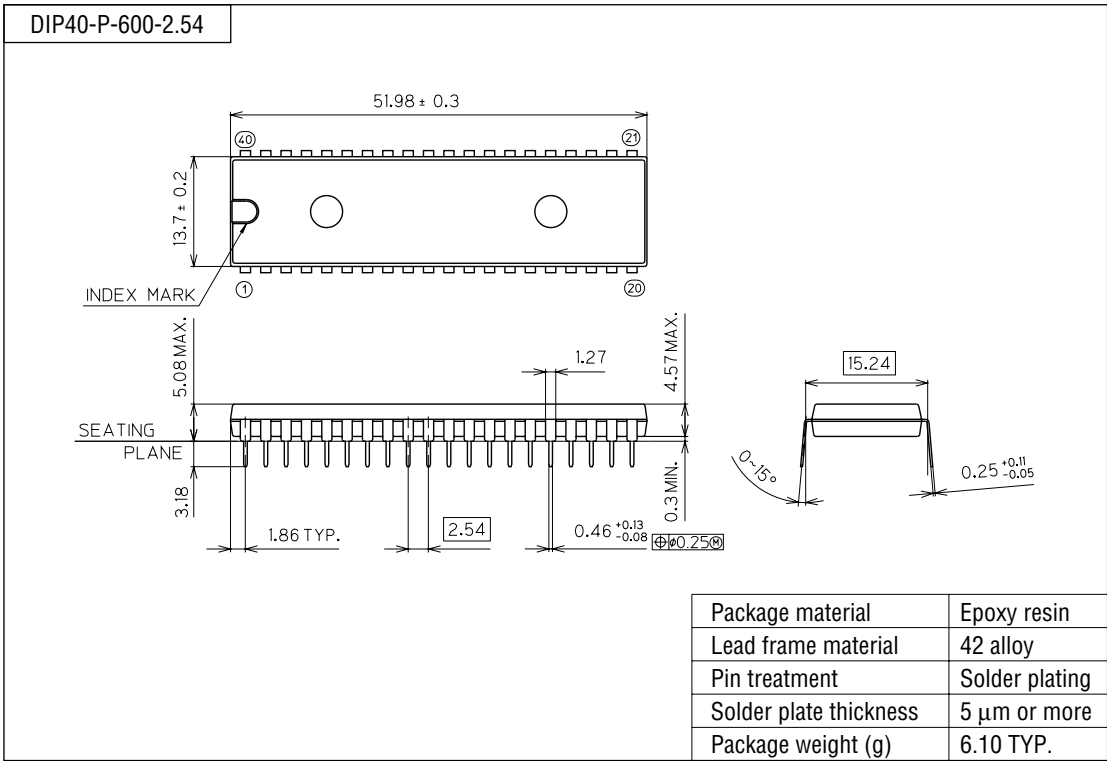
External clock waveform



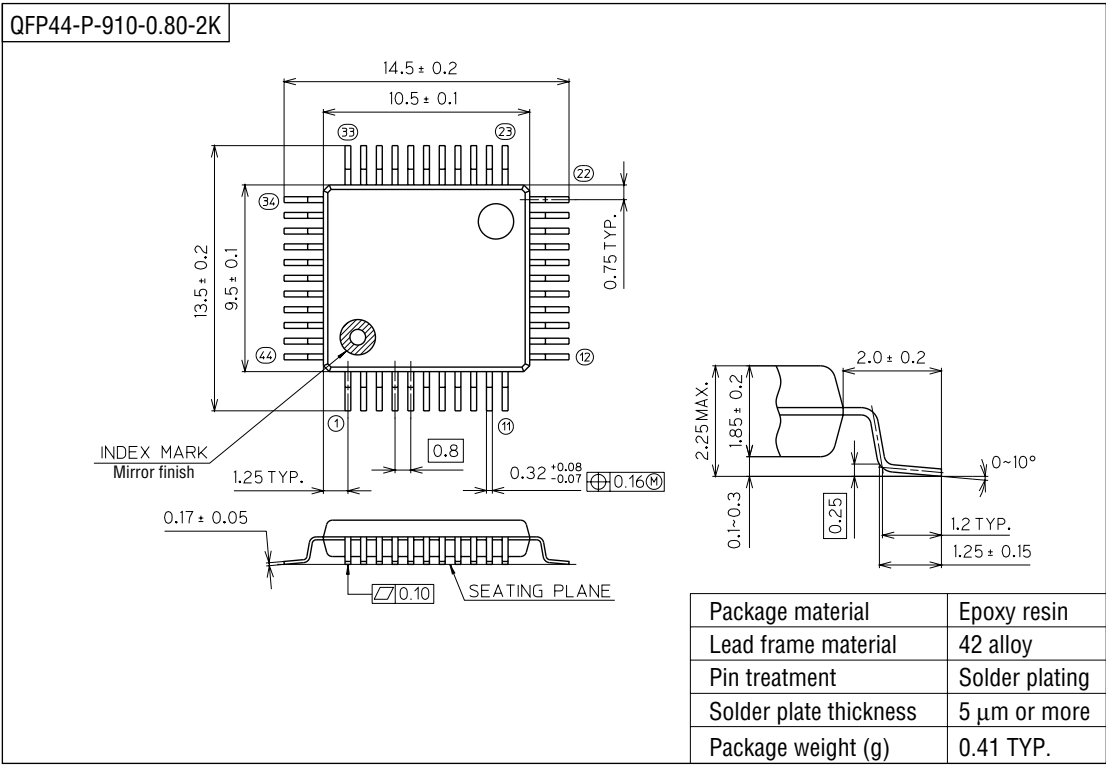
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PACKAGE DIMENSIONS

(Unit : mm)



(Unit : mm)

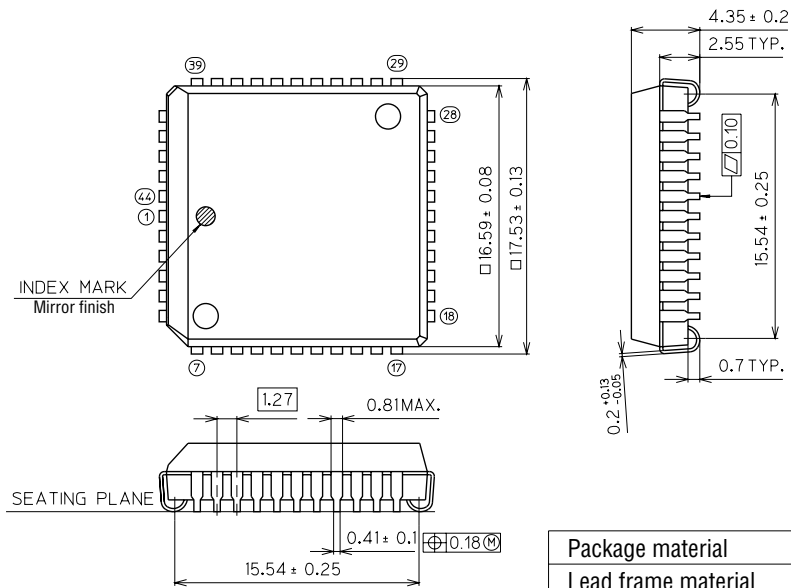


Notes for Mounting the Surface Mount Type Package

The SOP, QFP, TSOP, TQFP, LQFP, SOJ, QFJ (PLCC), SHP, and BGA are surface mount type packages, which are very susceptible to heat in reflow mounting and humidity absorbed in storage. Therefore, before you perform reflow mounting, contact Oki's responsible sales person on the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

(Unit : mm)

QFJ44-P-S650-1.27



Package material	Epoxy resin
Lead frame material	Cu alloy
Pin treatment	Solder plating
Solder plate thickness	5 μm or more
Package weight (g)	2.00 TYP.

Notes for Mounting the Surface Mount Type Package

The SOP, QFP, TSOP, TQFP, LQFP, SOJ, QFJ (PLCC), SHP, and BGA are surface mount type packages, which are very susceptible to heat in reflow mounting and humidity absorbed in storage. Therefore, before you perform reflow mounting, contact Oki's responsible sales person on the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

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1. The information contained herein can change without notice owing to product and/or technical improvements. Before using the product, please make sure that the information being referred to is up-to-date.
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